



SILEGO

SLG59M1460V

30 m Ω , 2.0 A Nanopower Mobile Integrated Power Switch with Discharge

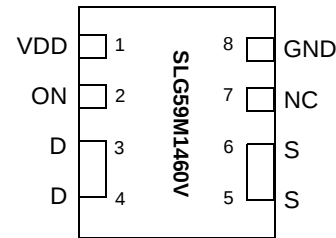
General Description

The SLG59M1460V is a 30 m Ω 2.0 A single-channel load switch that is able to switch 0.85 to 3.3 V power rails. The product is packaged in an ultra-small 1.0 x 1.6 mm package.

Features

- 1.0 x 1.6 x 0.55 mm STDFN 8L package (2 fused pins for drain and 2 fused pins for source)
- Logic level ON pin capable of supporting 0.85 V CMOS Logic
- Discharged Load when off
- Fast Turn On time
- Low RDS_{ON} while supporting 2.0 A
- Pb-Free / Halogen-Free / RoHS compliant
- Operating Temperature: -20 °C to 70°C
- Operating Voltage: 2.5 V to 5.25 V

Pin Configuration

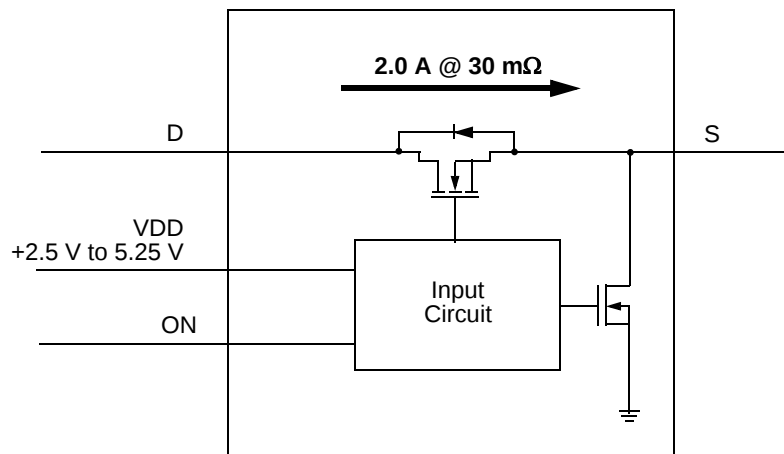


8-pin STDFN
(Top View)

Applications

- Watch Power Rail Switching
- Tablet Power Rail Switching
- Smartphone Power Rail Switching

Block Diagram





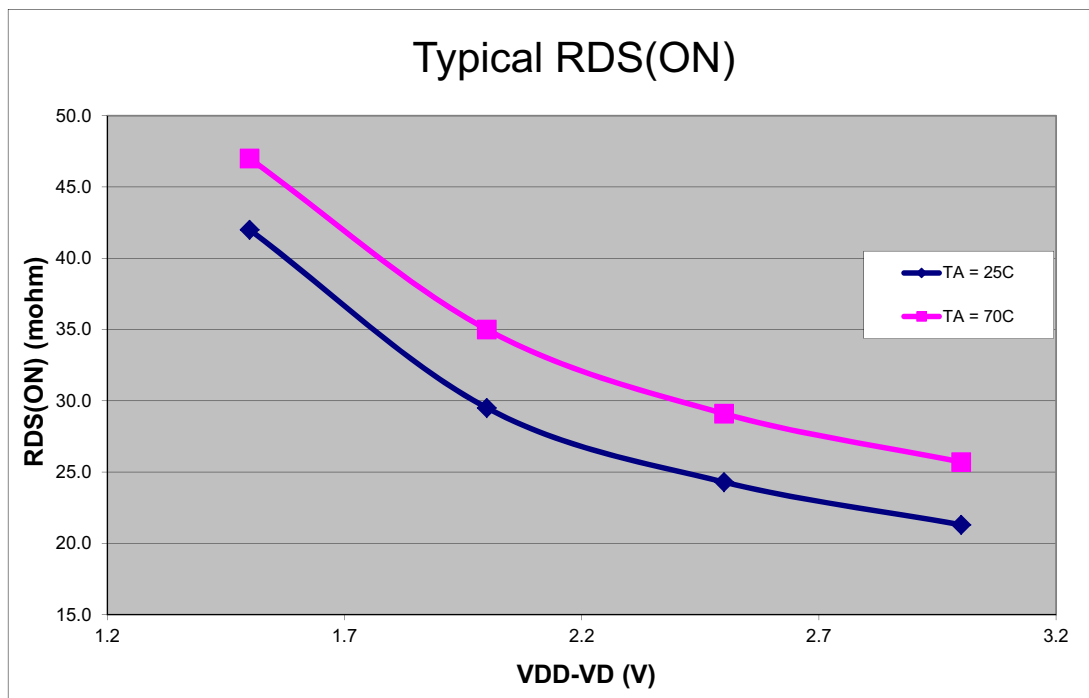
Pin Description

Pin #	Pin Name	Type	Pin Description
1	VDD	PWR	VDD power for load switch control (2.5 V to 5.25 V)
2	ON	Input	Turns MOSFET ON (4 M Ω pull down resistor) CMOS input with VIL < 0.3 V, VIH > 0.85 V
3	D	MOSFET	Drain of Power MOSFET (fused with pin 4)
4	D	MOSFET	Drain of Power MOSFET (fused with pin 3)
5	S	MOSFET	Source of Power MOSFET (fused with pin 6)
6	S	MOSFET	Source of Power MOSFET (fused with pin 5)
7	NC	NC	No Connect. Must leave this pin floating. Do not connect to VDD or GND
8	GND	GND	Ground

Ordering Information

Part Number	Type	Production Flow
SLG59M1460V	STDFN 8L	Commercial, -20 °C to 70 °C
SLG59M1460VTR	STDFN 8L (Tape and Reel)	Commercial, -20 °C to 70 °C

SLG59M1460V RDS_{ON}





Absolute Maximum Ratings

Parameter	Description	Conditions	Min.	Typ.	Max.	Unit
V_{DD}	Power Supply		--	--	7	V
T_S	Storage Temperature		-65	--	150	°C
ESD_{HBM}	ESD Protection	Human Body Model	2000	--	--	V
W_{DIS}	Package Power Dissipation		--	--	0.4	W
MOSFET IDS_{PK}	Peak Current from Drain to Source	For no more than 1 ms with 1% duty cycle	--	--	3.5	A

Note: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

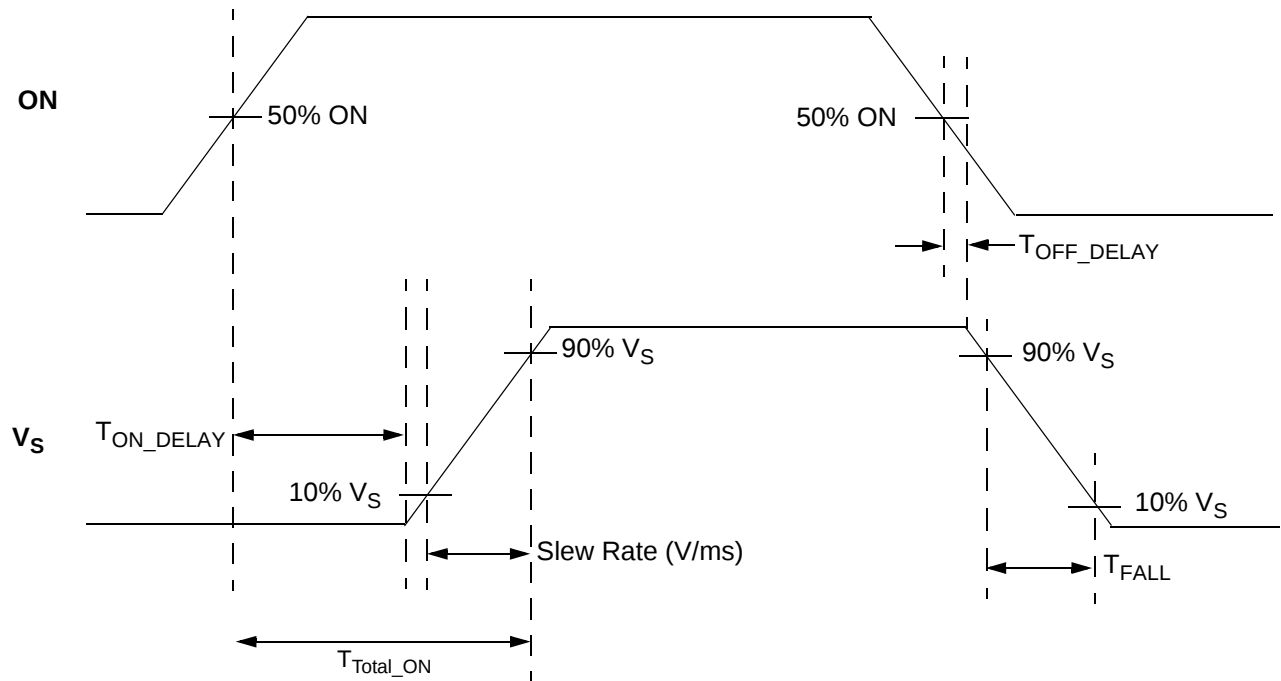
Electrical Characteristics

$T_A = -20$ to 70 °C (unless otherwise stated)

Parameter	Description	Conditions	Min.	Typ.	Max.	Unit
V_{DD}	Power Supply Voltage	-20 to 70°C	2.5	--	5.25	V
I_{DD}	Power Supply Current (PIN 1)	when OFF	--	30	100	nA
		when ON, No load	--	150	300	nA
$R_{DS_{ON}}$	Static Drain to Source ON Resistance	T_A 25°C @ 100 mA, $V_{DD} - V_D = 1.5$ V	--	42.0	46.0	mΩ
		T_A 25°C @ 100 mA, $V_{DD} - V_D = 2.0$ V	--	29.5	35.0	mΩ
		T_A 25°C @ 100 mA, $V_{DD} - V_D = 2.5$ V	--	24.3	30.0	mΩ
		T_A 25°C @ 100 mA, $V_{DD} - V_D = 3.0$ V	--	21.3	25.0	mΩ
$R_{DS_{ON}}$	Static Drain to Source ON Resistance	T_A 70°C @ 100 mA, $V_{DD} - V_D = 1.5$ V	--	47.0	50.0	mΩ
		T_A 70°C @ 100 mA, $V_{DD} - V_D = 2.0$ V	--	35.0	38.0	mΩ
		T_A 70°C @ 100 mA, $V_{DD} - V_D = 2.5$ V	--	29.1	32.0	mΩ
		T_A 70°C @ 100 mA, $V_{DD} - V_D = 3.0$ V	--	25.7	29.0	mΩ
IDS	Operating Current	$V_D = 1.0$ V to 3.3 V	--	--	2.0	A
V_D	Drain Voltage		0.85	--	$V_{DD} - 1.5$	V
T_{Total_ON}	Total Turn On Time	50% ON to 90% V_S , $V_{DD} = 2.5$ V, $V_D = 1.0$ V, 10 μF Load, $IDS = 100$ mA	--	64	75	μs
		50% ON to 90% V_S , $V_{DD} = 5.25$ V, $V_D = 1.0$ V, 10 μF Load, $IDS = 100$ mA	--	28	40	μs
$T_{SLEWRATE}$	Slew Rate	10% V_S to 90% V_S , $V_{DD} = 2.5$ V, $V_D = 1.0$ V, 10 μF Load, $IDS = 100$ mA	--	23	25	V/ms
		10% V_S to 90% V_S , $V_{DD} = 5.25$ V, $V_D = 1.0$ V, 10 μF Load, $IDS = 100$ mA	--	64	70	V/ms
CAP_{SOURCE}	Source Cap	Source to GND	--	--	10	μF
R_{DIS}	Discharge Resistance		100	150	300	Ω
ON_ V_{IH}	High Input Voltage on ON pin		0.85	--	V_{DD}	V
ON_ V_{IL}	Low Input Voltage on ON pin		-0.3	0	0.3	V
T_{OFF_Delay}	OFF Delay Time	50% ON to V_S Fall, $V_{DD} = 2.5$ V, $V_D = 1.0$ V, 0.1 μF Load, 10 Ω	--	36	45	μs
T_{FALL}	V_S Fall Time	90% V_S to 10% V_S , $V_{DD} = 2.5$ V, $V_D = 1.0$ V, 0.1 μF Load, 10 Ω	--	42	--	μs

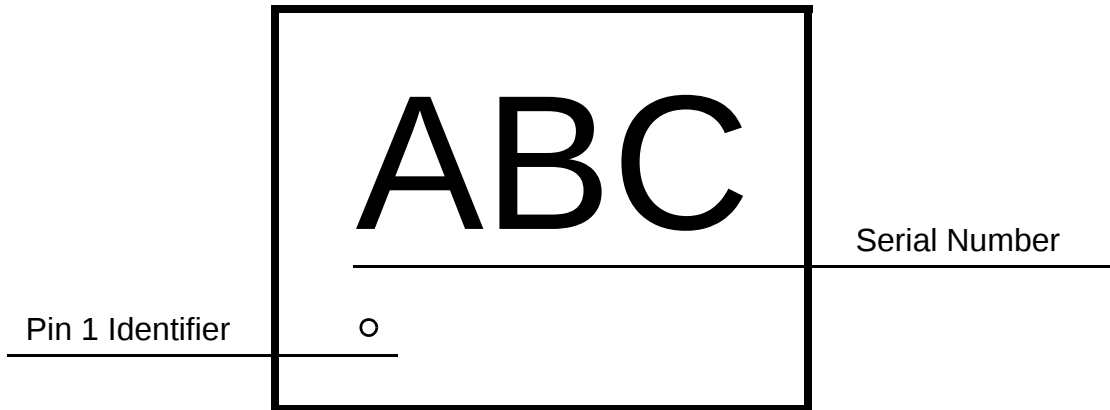


T_{Total_ON} , T_{ON_Delay} and Slew Rate Measurement





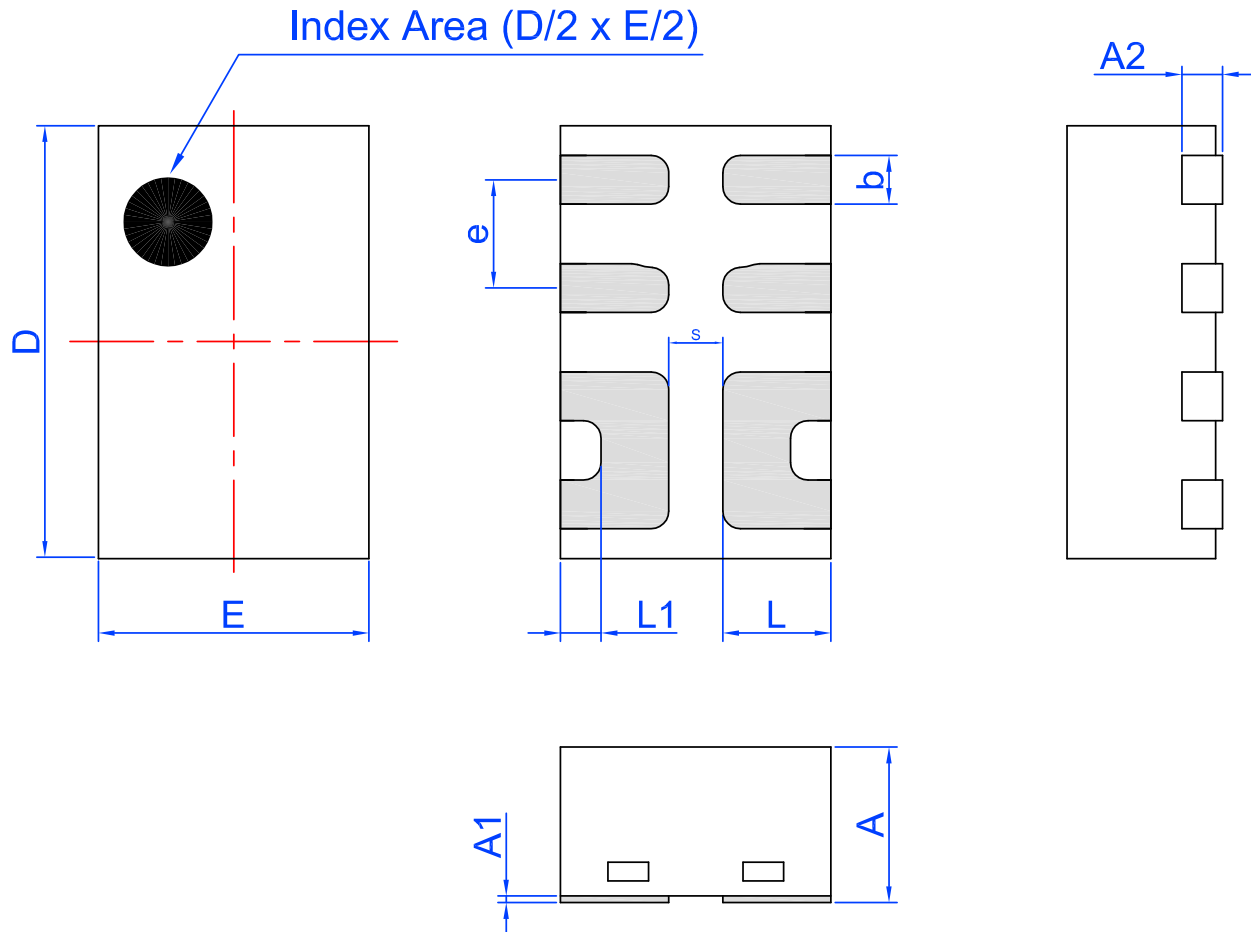
Package Top Marking System Definition





Package Drawing and Dimensions

8 Lead STDFN Package 1.0 x 1.6 mm (Fused Lead)



Unit: mm

Symbol	Min	Nom.	Max	Symbol	Min	Nom.	Max
A	0.50	0.55	0.60	D	1.55	1.60	1.65
A1	0.005	-	0.060	E	0.95	1.00	1.05
A2	0.10	0.15	0.20	L	0.35	0.40	0.45
b	0.13	0.18	0.23	L1	0.10	0.15	0.20
e	0.40 BSC			S	0.2 REF		

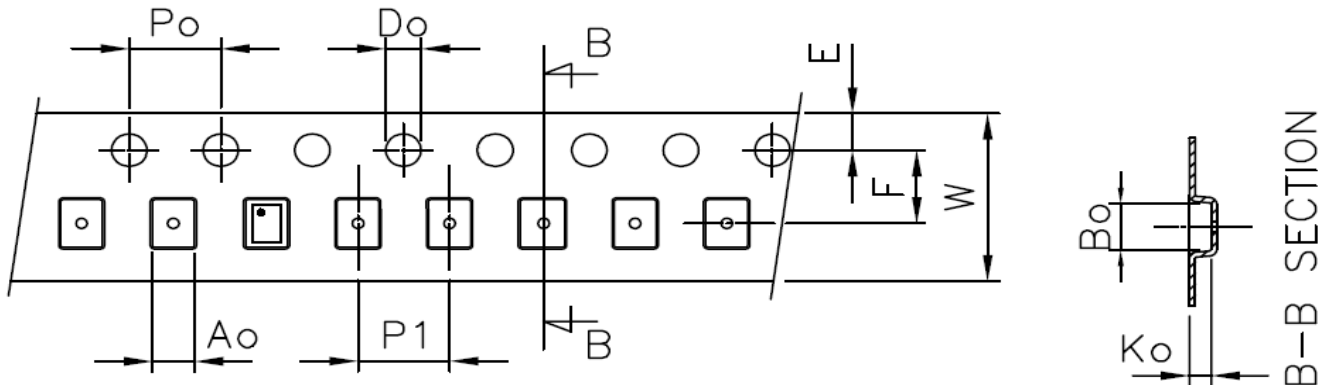


Tape and Reel Specifications

Package Type	# of Pins	Nominal Package Size [mm]	Max Units		Reel & Hub Size [mm]	Leader (min)		Trailer (min)		Tape Width [mm]	Part Pitch [mm]
			per Reel	per Box		Pockets	Length [mm]	Pockets	Length [mm]		
STDFN 8L 1x1.6mm 0.4P FC Green	8	1.0 x 1.6 x 0.55	3,000	3,000	178 / 60	100	400	100	400	8	4

Carrier Tape Drawing and Dimensions

Package Type	Pocket BTM Length	Pocket BTM Width	Pocket Depth	Index Hole Pitch	Pocket Pitch	Index Hole Diameter	Index Hole to Tape Edge	Index Hole to Pocket Center	Tape Width
	A0	B0	K0	P0	P1	D0	E	F	W
STDFN 8L 1x1.6mm 0.4P FC Green	1.12	1.72	0.7	4	4	1.55	1.75	3.5	8



Recommended Reflow Soldering Profile

Please see IPC/JEDEC J-STD-020: latest revision for reflow profile based on package volume of 0.88 mm³ (nominal). More information can be found at www.jedec.org.



Revision History

Date	Version	Change
11/5/2015	1.01	Updated VD min to 0.85 V
9/14/2015	1.00	Production Release

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9